

SN74AHC1G125-Q1 車載用、シングル・バス・バッファ・ゲート、3 ステート出力搭載

1 特長

- 車載アプリケーション用に AEC-Q100 認定済み:
 - デバイス温度グレード 1: -40°C ~ +125°C
 - デバイス HBM ESD 分類レベル 2
 - デバイス CDM ESD 分類レベル C4B
- 動作範囲: 2V ~ 5.5V
- 低消費電力、 I_{CC} の最大値 10μA
- 5V で ±8mA の出力駆動能力
- JESD 17 準拠で 250mA 超のラッチアップ性能

2 アプリケーション

- デジタル信号のイネーブルまたはディセーブル
- インジケータ LED の制御
- スイッチのデバウンス
- 低速またはノイズの多い入力信号の除去

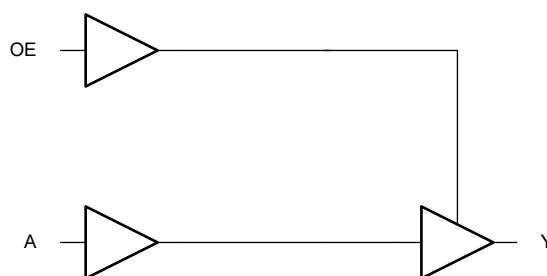
3 概要

SN74AHC1G126-Q1 は、3 ステート出力と電圧変換機能を内蔵したシングル・バッファ・ゲートです。このバッファはブール関数 $Y = A$ を正論理で実行します。OE ピンに High を印加することで、出力をハイ・インピーダンス状態にできます。

パッケージ情報

部品番号	パッケージ ⁽¹⁾	パッケージ・サイズ ⁽²⁾	本体サイズ ⁽³⁾
SN74AHC1G126-Q1	DBV (SOT-23, 5)	2.9mm × 2.8mm	2.9mm × 1.6mm
	DCK (SC70, 5)	2mm × 2.1mm	2mm × 1.25mm

- 利用可能なすべてのパッケージについては、データシートの末尾にある注文情報を参照してください。
- パッケージ・サイズ (長さ×幅) は公称値であり、該当する場合はピンも含まれます。
- 本体サイズ (長さ×幅) は公称値であり、ピンは含まれません。



概略論理図 (正論理)



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4 Revision History

Changes from Revision * (August 2023) to Revision A (October 2023)	Page
• 「パッケージ情報」表に DBV パッケージを追加	1
• Added DBV package to <i>Pin Configuration and Functions</i> section.....	3
• Added thermal values for DBV package: R θ JA = 278.0, R θ JC(top) = 180.5, R θ JB = 184.4, Ψ JT = 115.4, Ψ JB = 183.4, R θ JC(bot) = N/A, all values in °C/W	5

5 Pin Configuration and Functions

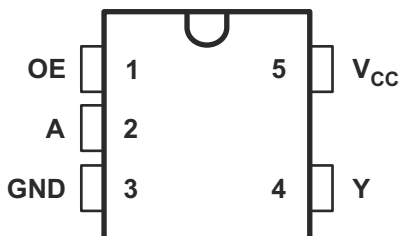


図 5-1. SN74AHC1G126-Q1 DBV Package, 5-Pin SOT-23; DCK Package, 5-Pin SC-70 (Top View)

表 5-1. Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
OE	1	I	Output enable. Active high
A	2	I	Input
GND	3	G	Ground
Y	4	O	Output
V _{CC}	5	P	Power Supply

(1) I = input, O = output, I/O = input or output, G = ground, P = power.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V_{CC}	Supply voltage	-0.5	7	V
V_I	Input voltage range	-0.5	7	V
V_O	Output voltage range	-0.5	$V_{CC} + 0.5$	V
V_O	Voltage range applied to any output in the high-impedance or power-off state	-0.5	4.6	V
I_{IK}	Input clamp current ⁽²⁾	$V_I < 0$	-20	mA
I_{OK}	Output clamp current ⁽²⁾	$V_O < 0$ or $V_O > V_{CC}$	20	mA
I_O	Continuous output current	$V_O = 0$ to V_{CC}	25	mA
I_O	Continuous output current through V_{CC} or GND	-50	50	mA
T_J	Junction temperature		150	°C
T_{stg}	Storage temperature	-65	150	°C

- (1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. Absolute maximum ratings do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If briefly operating outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not sustain damage, but it may not be fully functional. Operating the device in this manner may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

6.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per AEC Q100-002 ⁽¹⁾ HBM ESD Classification Level 2	±2000
		Charged device model (CDM), per AEC Q100-011 CDM ESD Classification Level C4B	±1000

- (1) AEC Q100-002 indicate that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	MAX	UNIT
V_{CC}	Supply Voltage		2	5.5	V
V_{IH}	high-level input voltage	$V_{CC} = 2\text{ V}$	1.5		V
		$V_{CC} = 3\text{ V}$	2.1		V
		$V_{CC} = 5.5\text{ V}$	3.85		V
V_{IL}	low-level input voltage	$V_{CC} = 2\text{ V}$		0.5	V
		$V_{CC} = 3\text{ V}$		0.9	V
		$V_{CC} = 5.5\text{ V}$		1.65	V
V_I	input voltage		0	5.5	V
V_O	output voltage		0	V_{CC}	V
I_{OH}	high-level output current	$V_{CC} = 2\text{ V}$		-50	μA
		$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$		-4	mA
		$V_{CC} = 5\text{ V} \pm 0.5\text{ V}$		-8	mA

6.3 Recommended Operating Conditions (続き)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	MAX	UNIT
I_{OL}	low-level output current	$V_{CC} = 2\text{ V}$		50	μA
		$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$		4	mA
		$V_{CC} = 5\text{ V} \pm 0.5\text{ V}$		8	mA
$\Delta t/\Delta v$	input transition rise or fall rate	$V_{CC} = 3.3\text{ V} \pm 0.3$		100	nS/V
$\Delta t/\Delta v$	input transition rise or fall rate	$V_{CC} = 5\text{ V} \pm 0.5\text{ V}$		20	nS/V
T_A	Operating free-air temperature		-55	125	$^{\circ}\text{C}$

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		SN74AHC1G126-Q1		UNIT
		DBV (SOT-23)	DCK (SC70)	
		5 PINS	5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	278.0	293.4	$^{\circ}\text{C/W}$
$R_{\theta JC(\text{top})}$	Junction-to-case (top) thermal resistance	180.5	208.8	$^{\circ}\text{C/W}$
$R_{\theta JB}$	Junction-to-board thermal resistance	184.4	180.6	$^{\circ}\text{C/W}$
Ψ_{JT}	Junction-to-top characterization parameter	115.4	120.6	$^{\circ}\text{C/W}$
Ψ_{JB}	Junction-to-board characterization parameter	183.4	179.5	$^{\circ}\text{C/W}$
$R_{\theta JC(\text{bot})}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	$^{\circ}\text{C/W}$

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V_{CC}	$T_A = 25^{\circ}\text{C}$			-40°C to 125°C			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{OH}	$I_{OH} = -50\text{ }\mu\text{A}$	$V_{CC} = 2\text{ V}$	1.9			1.9			V
	$I_{OH} = -50\text{ }\mu\text{A}$	$V_{CC} = 3\text{ V}$	2.9			2.9			V
	$I_{OH} = -50\text{ }\mu\text{A}$	$V_{CC} = 4.5\text{ V}$	4.4			4.4			V
	$I_{OH} = -4\text{ mA}$	$V_{CC} = 3\text{ V}$	2.58			2.48			V
	$I_{OH} = -8\text{ mA}$	$V_{CC} = 4.5\text{ V}$	3.94			3.8			V
V_{OL}	$I_{OH} = 50\text{ }\mu\text{A}$	$V_{CC} = 2\text{ V}$			0.1			0.1	V
	$I_{OH} = 50\text{ }\mu\text{A}$	$V_{CC} = 3\text{ V}$			0.1			0.1	V
	$I_{OH} = 50\text{ }\mu\text{A}$	$V_{CC} = 4.5\text{ V}$			0.1			0.1	V
	$I_{OH} = 4\text{ mA}$	$V_{CC} = 3\text{ V}$			0.36			0.44	V
	$I_{OH} = 8\text{ mA}$	$V_{CC} = 4.5\text{ V}$			0.36			0.44	V
I_I	$V_I = 5.5\text{ V}$ or GND	0 V to 5.5 V	-0.1		0.1	-1		1	μA
I_{OZ}	$V_O = V_{CC}$ or GND	5.5 V	-0.25		0.25	-2.5		2.5	μA
I_{CC}	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			1			4	μA
C_i	$V_I = V_{CC}$ or GND	5 V		1.7	10				pF
C_O	$V_O = V_{CC}$ or GND	5 V		3					pF
C_{PD}	Power dissipation capacitance	5 V		14					pF

6.6 Switching Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	V _{CC}	T _A = 25°C			-40°C to 85°C			-40°C to 125°C			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t _{PHL}	A	Y	C _L = 15 pF	3.3 V ± 0.3 V	5.6	8		1	9.5		1	10		ns
t _{PHZ}	OE	Y	C _L = 15 pF	3.3 V ± 0.3 V	5.4	8		1	9.5		1	10		ns
t _{PLH}	A	Y	C _L = 15 pF	3.3 V ± 0.3 V	5.6	8		1	9.5		1	10		ns
t _{PLZ}	OE	Y	C _L = 15 pF	3.3 V ± 0.3 V	7	9.7		1	11.5		1	12.5		ns
t _{PZH}	OE	Y	C _L = 15 pF	3.3 V ± 0.3 V	5.4	8		1	9.5		1	10		ns
t _{PZL}	OE	Y	C _L = 15 pF	3.3 V ± 0.3 V	5.4	8		1	9.5		1	10		ns
t _{PHL}	A	Y	C _L = 50 pF	3.3 V ± 0.3 V	8.5	11.1		1	13		1	14		ns
t _{PHZ}	OE	Y	C _L = 50 pF	3.3 V ± 0.3 V	9.5	13.2		1	15		1	16		ns
t _{PLH}	A	Y	C _L = 50 pF	3.3 V ± 0.3 V	8.1	11.5		1	13		1	14		ns
t _{PLZ}	OE	Y	C _L = 50 pF	3.3 V ± 0.3 V	9.5	13.2		1	15		1	16		ns
t _{PZH}	OE	Y	C _L = 50 pF	3.3 V ± 0.3 V	7.9	11.5		1	13		1	14		ns
t _{PZL}	OE	Y	C _L = 50 pF	3.3 V ± 0.3 V	7.9	11.5		1	13		1	14		ns
t _{PHL}	A	Y	C _L = 15 pF	5 V ± 0.5 V	3.8	5.5		1	6.5		1	7		ns
t _{PHZ}	OE	Y	C _L = 15 pF	5 V ± 0.5 V	4.6	6.8		1	8		1	8.5		ns
t _{PLH}	A	Y	C _L = 15 pF	5 V ± 0.5 V	3.8	5.5		1	6.5		1	7		ns
t _{PLZ}	OE	Y	C _L = 15 pF	5 V ± 0.5 V	4.6	6.8		1	8		1	8.5		ns
t _{PZH}	OE	Y	C _L = 15 pF	5 V ± 0.5 V	3.6	5.1		1	6		1	6.5		ns
t _{PZL}	OE	Y	C _L = 15 pF	5 V ± 0.5 V	3.6	5.1		1	6		1	6.5		ns
t _{PHL}	A	Y	C _L = 50 pF	5 V ± 0.5 V	5.3	7.5		1	8.5		1	9.5		ns
t _{PHZ}	OE	Y	C _L = 50 pF	5 V ± 0.5 V	6.1	8.8		1	10		1	11		ns
t _{PLH}	A	Y	C _L = 50 pF	5 V ± 0.5 V	5.3	7.5		1	8.5		1	9.5		ns
t _{PLZ}	OE	Y	C _L = 50 pF	5 V ± 0.5 V	6.1	8.8		1	10		1	11		ns
t _{PZH}	OE	Y	C _L = 50 pF	5 V ± 0.5 V	5.1	7.1		1	8		1	9		ns
t _{PZL}	OE	Y	C _L = 50 pF	5 V ± 0.5 V	5.1	7.1		1	8		1	9		ns

6.7 Typical Characteristics

$T_A = 25^\circ\text{C}$ (unless otherwise noted)

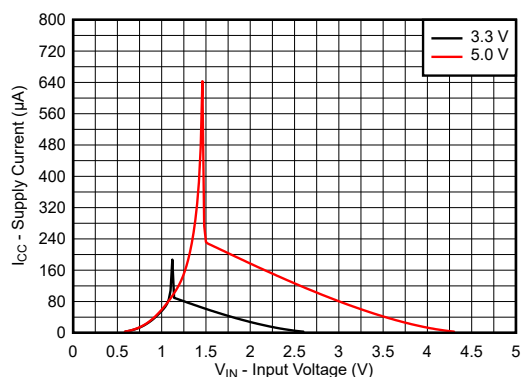


図 6-1. Supply Current Across Input Voltage 3.3-V and 5.0-V Supply

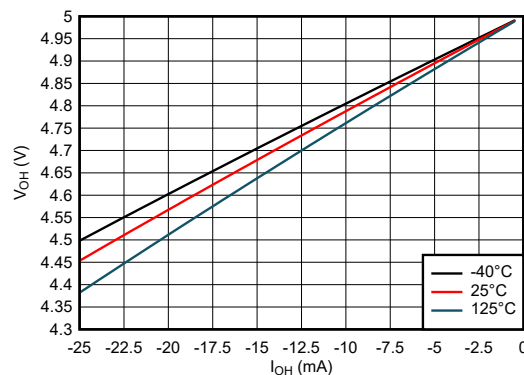


図 6-2. Output Voltage vs Current in HIGH State; 5-V Supply

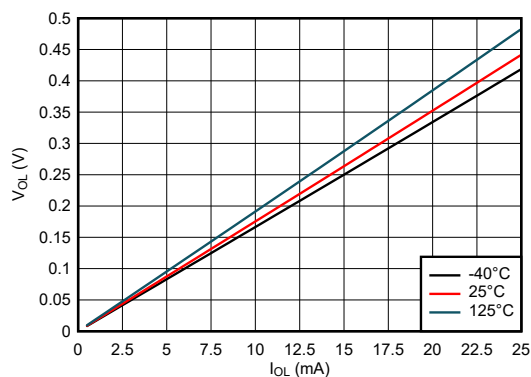


図 6-3. Output Voltage vs Current in LOW State; 5-V Supply

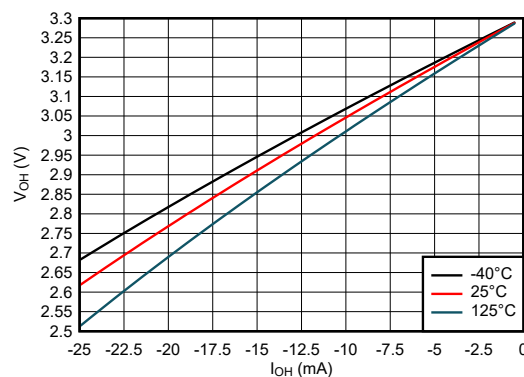


図 6-4. Output Voltage vs Current in HIGH State; 3.3-V Supply

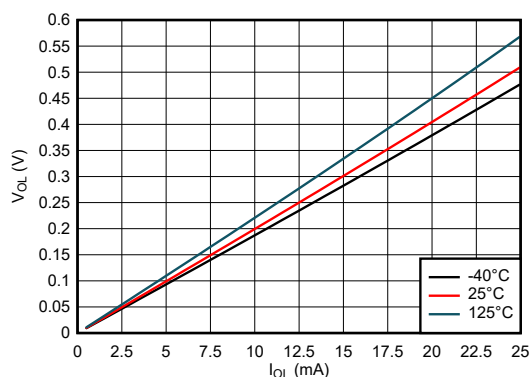


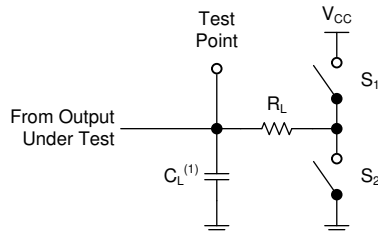
図 6-5. Output Voltage vs Current in LOW State; 3.3-V Supply

7 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: $PRR \leq 1 \text{ MHz}$, $Z_O = 50 \Omega$.

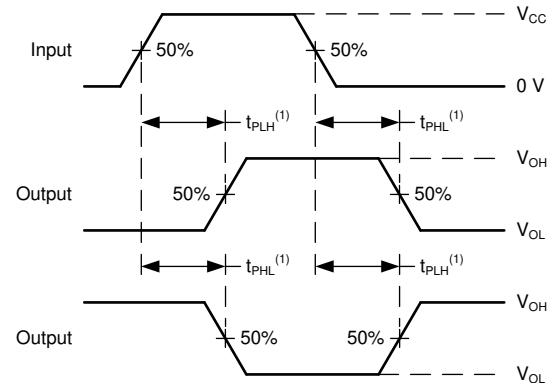
For clock inputs, $f_{\max}$ is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.



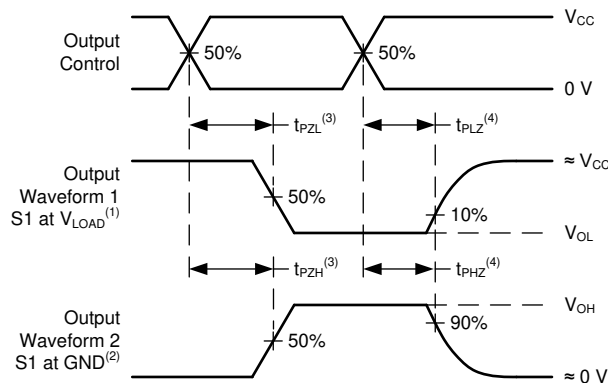
(1) C_L includes probe and test-fixture capacitance.

7-1. Load Circuit for 3-State Outputs



(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd} .

7-2. Voltage Waveforms Propagation Delays



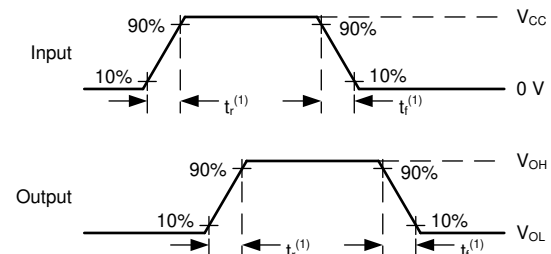
(1) S1 = CLOSED, S2 = OPEN.

(2) S1 = OPEN, S2 = CLOSED.

(3) The greater between t_{PZL} and t_{PZH} is the same as t_{en} .

(4) The greater between t_{PLZ} and t_{PHZ} is the same as t_{dis} .

7-3. Voltage Waveforms Propagation Delays



(1) The greater between t_r and t_f is the same as t_t .

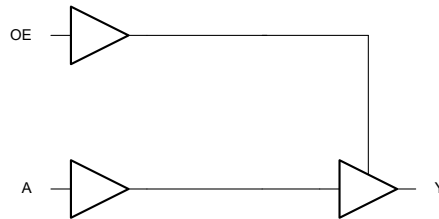
7-4. Voltage Waveforms, Input and Output Transition Times

8 Detailed Description

8.1 Overview

The SN74AHC1G126-Q1 is a single buffer gate with 3-state outputs and integrated voltage translation. This buffer performs the Boolean function $Y = A$ in positive logic. The outputs can be placed into a Hi-Z state by applying a High on the $\overline{OE}$ pin. The output level is referenced to the supply voltage (V_{CC}) and supports 1.8-V, 2.5-V, 3.3-V, and 5-V CMOS levels.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Standard CMOS Inputs

This device includes standard CMOS inputs. Standard CMOS inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics*. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings*, and the maximum input leakage current, given in the *Electrical Characteristics*, using Ohm's law ($R = V \div I$).

Standard CMOS inputs require that input signals transition between valid logic states quickly, as defined by the input transition time or rate in the *Recommended Operating Conditions* table. Failing to meet this specification will result in excessive power consumption and could cause oscillations. More details can be found in [Implications of Slow or Floating CMOS Inputs](#).

Do not leave standard CMOS inputs floating at any time during operation. Unused inputs must be terminated at V_{CC} or GND. If a system will not be actively driving an input at all times, then a pull-up or pull-down resistor can be added to provide a valid input voltage during these times. The resistor value will depend on multiple factors; a 10-k Ω resistor, however, is recommended and will typically meet all requirements.

8.3.2 Balanced CMOS 3-State Outputs

This device includes balanced CMOS 3-state outputs. Driving high, driving low, and high impedance are the three states that these outputs can be in. The term *balanced* indicates that the device can sink and source similar currents. The drive capability of this device may create fast edges into light loads, so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. It is important for the output power of the device to be limited to avoid damage due to overcurrent. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

When placed into the high-impedance mode, the output will neither source nor sink current, with the exception of minor leakage current as defined in the *Electrical Characteristics* table. In the high-impedance state, the output voltage is not controlled by the device and is dependent on external factors. If no other drivers are connected to the node, then this is known as a floating node and the voltage is unknown. A pull-up or pull-down resistor can be connected to the output to provide a known voltage at the output while it is in the high-impedance state. The value of the resistor will depend on multiple factors, including parasitic capacitance and power consumption limitations. Typically, a 10-k Ω resistor can be used to meet these requirements.

Unused 3-state CMOS outputs should be left disconnected.

8.3.3 Clamp Diode Structure

The outputs to this device have both positive and negative clamping diodes, and the inputs to this device have negative clamping diodes only as shown in 図 8-1.

注意

Voltages beyond the values specified in the *Absolute Maximum Ratings* table can cause damage to the device. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

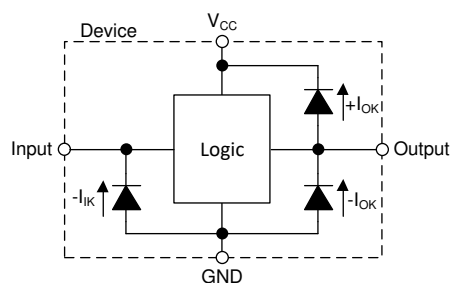


図 8-1. Electrical Placement of Clamping Diodes for Each Input and Output

8.4 Device Functional Modes

表 8-1 lists the functional modes of the SN74AHC1G126-Q1.

表 8-1. Function Table

INPUTS ⁽¹⁾		OUTPUT Y
A	OE	
H	H	H
L	H	L
X	L	Z

(1) H = high voltage level, L = low voltage level, X = do not care, Z = high impedance

9 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

In this application, a buffer with a 3-state output is used to disable a data signal as shown in the *Typical Application Block Diagram*.

9.2 Typical Application

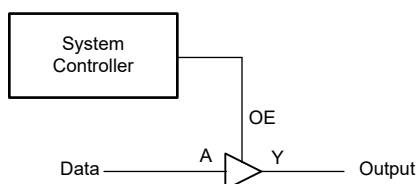


図 9-1. Typical Application Block Diagram

9.2.1 Design Requirements

9.2.1.1 Power Considerations

Ensure the desired supply voltage is within the range specified in the *Recommended Operating Conditions*. The supply voltage sets the electrical characteristics of the device as described in the *Electrical Characteristics* section.

The positive voltage supply must be capable of sourcing current equal to the total current to be sourced by all outputs of the SN74AHC1G126-Q1 plus the maximum static supply current, I_{CC} , listed in the *Electrical Characteristics*, and any transient current required for switching. The logic device can only source as much current that is provided by the positive supply source. Be sure to not exceed the maximum total current through V_{CC} listed in the *Absolute Maximum Ratings*.

The ground must be capable of sinking current equal to the total current to be sunk by all outputs of the SN74AHC1G126-Q1 plus the maximum supply current, I_{CC} , listed in the *Electrical Characteristics*, and any transient current required for switching. The logic device can only sink as much current that can be sunk into its ground connection. Be sure to not exceed the maximum total current through GND listed in the *Absolute Maximum Ratings*.

The SN74AHC1G126-Q1 can drive a load with a total capacitance less than or equal to 50 pF while still meeting all of the data sheet specifications. Larger capacitive loads can be applied; however, it is not recommended to exceed 50 pF.

The SN74AHC1G126-Q1 can drive a load with total resistance described by $R_L \geq V_O / I_O$, with the output voltage and current defined in the *Electrical Characteristics* table with V_{OH} and V_{OL} . When outputting in the HIGH state, the output voltage in the equation is defined as the difference between the measured output voltage and the supply voltage at the V_{CC} pin.

Total power consumption can be calculated using the information provided in the [CMOS Power Consumption and Cpd Calculation](#) application note.

Thermal increase can be calculated using the information provided in the [Thermal Characteristics of Standard Linear and Logic \(SLL\) Packages and Devices](#) application note.

注意

The maximum junction temperature, $T_{J(max)}$ listed in the *Absolute Maximum Ratings*, is an additional limitation to prevent damage to the device. Do not violate any values listed in the *Absolute Maximum Ratings*. These limits are provided to prevent damage to the device.

9.2.1.2 Input Considerations

Input signals must cross $V_{IL(max)}$ to be considered a logic LOW, and $V_{IH(min)}$ to be considered a logic HIGH. Do not exceed the maximum input voltage range found in the *Absolute Maximum Ratings*.

Unused inputs must be terminated to either V_{CC} or ground. The unused inputs can be directly terminated if the input is completely unused, or they can be connected with a pull-up or pull-down resistor if the input will be used sometimes, but not always. A pull-up resistor is used for a default state of HIGH, and a pull-down resistor is used for a default state of LOW. The drive current of the controller, leakage current into the SN74AHC1G126-Q1 (as specified in the *Electrical Characteristics*), and the desired input transition rate limits the resistor size. A 10-k Ω resistor value is often used due to these factors.

The SN74AHC1G126-Q1 has CMOS inputs and thus requires fast input transitions to operate correctly, as defined in the *Recommended Operating Conditions* table. Slow input transitions can cause oscillations, additional power consumption, and reduction in device reliability.

Refer to the *Feature Description* section for additional information regarding the inputs for this device.

9.2.1.3 Output Considerations

The positive supply voltage is used to produce the output HIGH voltage. Drawing current from the output will decrease the output voltage as specified by the V_{OH} specification in the *Electrical Characteristics*. The ground voltage is used to produce the output LOW voltage. Sinking current into the output will increase the output voltage as specified by the V_{OL} specification in the *Electrical Characteristics*.

Push-pull outputs that could be in opposite states, even for a very short time period, should never be connected directly together. This can cause excessive current and damage to the device.

Two channels within the same device with the same input signals can be connected in parallel for additional output drive strength.

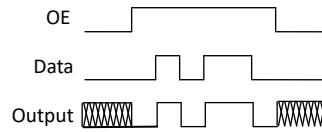
Unused outputs can be left floating. Do not connect outputs directly to V_{CC} or ground.

Refer to the *Feature Description* section for additional information regarding the outputs for this device.

9.2.2 Detailed Design Procedure

1. Add a decoupling capacitor from V_{CC} to GND. The capacitor needs to be placed physically close to the device and electrically close to both the V_{CC} and GND pins. An example layout is shown in the *Layout* section.
2. Ensure the capacitive load at the output is ≤ 50 pF. This is not a hard limit; by design, however, it will optimize performance. This can be accomplished by providing short, appropriately sized traces from the SN74AHC1G126-Q1 to one or more of the receiving devices.
3. Ensure the resistive load at the output is larger than $(V_{CC} / I_{O(max)}) \Omega$. Doing this will prevent the maximum output current from the *Absolute Maximum Ratings* from being violated. Most CMOS inputs have a resistive load measured in M Ω ; much larger than the minimum calculated previously.
4. Thermal issues are rarely a concern for logic gates; the power consumption and thermal increase, however, can be calculated using the steps provided in the application report, [CMOS Power Consumption and Cpd Calculation](#).

9.2.3 Application Curves



9-2. Application Timing Diagram

9.3 Power Supply Recommendations

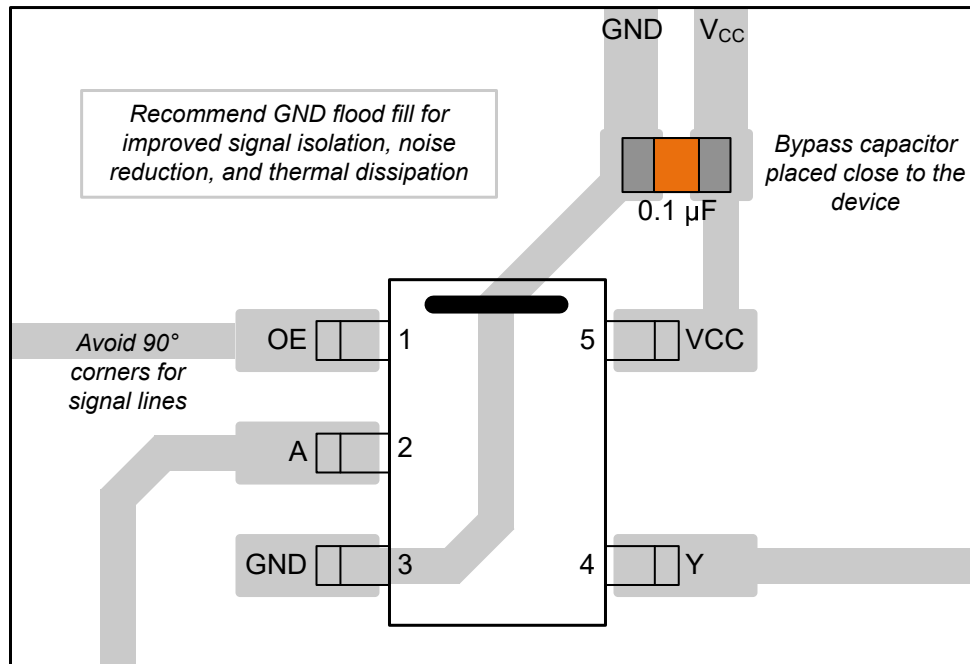
The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- μF capacitor is recommended for this device. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. The 0.1- μF and 1- μF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in the following layout example.

9.4 Layout

9.4.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices, inputs must never be left floating. In many cases, functions or parts of functions of digital logic devices are unused (for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used). Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC} , whichever makes more sense for the logic function or is more convenient.

9.4.2 Layout Example



9-3. Example Layout for the SN74AHC1G126-Q1

10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

10.1 Documentation Support

10.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [CMOS Power Consumption and Cpd Calculation application note](#)
- Texas Instruments, [Designing With Logic application note](#)
- Texas Instruments, [Thermal Characteristics of Standard Linear and Logic \(SLL\) Packages and Devices application note](#)
- Texas Instruments, [Implications of Slow or Floating CMOS Inputs application note](#)

10.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、www.tij.co.jp のデバイス製品フォルダを開いてください。[通知] をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。変更の詳細については、改訂されたドキュメントに含まれている改訂履歴をご覧ください。

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10.6 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
CAHC1G126QDBVRQ1	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	39NH
CAHC1G126QDBVRQ1.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	39NH
CAHC1G126QDCKRQ1	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1QI
CAHC1G126QDCKRQ1.A	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1QI

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74AHC1G126-Q1 :

- Catalog : [SN74AHC1G126](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CAHC1G126QDBVRQ1	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
CAHC1G126QDCKRQ1	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CAHC1G126QDBVRQ1	SOT-23	DBV	5	3000	210.0	185.0	35.0
CAHC1G126QDCKRQ1	SC70	DCK	5	3000	190.0	190.0	30.0



SOT - 1.1 max height

Technical drawing of a mechanical part showing three views: front, side, and top.

Front View:

- Overall dimensions: 2.4 (width) x 2.15 (height).
- Internal dimensions: 1.4 (width), 1.1 (width), 1.3 (height), 1.3 (height).
- Feature 1: PIN 1 INDEX AREA (hatched area).
- Feature 2: 2X 0.65 (width).
- Feature 3: 5X 0.33 / 0.15 (width).
- Feature 4: (0.15) (width), (0.1) (width).
- Feature 5: (0.15) (width).
- Feature 6: (0.1) (width).
- Feature 7: (0.15) (width).
- Feature 8: (0.1) (width).
- Feature 9: (0.15) (width).
- Feature 10: (0.1) (width).
- Feature 11: (0.15) (width).
- Feature 12: (0.1) (width).
- Feature 13: (0.15) (width).
- Feature 14: (0.1) (width).
- Feature 15: (0.15) (width).
- Feature 16: (0.1) (width).
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- Feature 18: (0.1) (width).
- Feature 19: (0.15) (width).
- Feature 20: (0.1) (width).
- Feature 21: (0.15) (width).
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- Feature 93: (0.15) (width).
- Feature 94: (0.1) (width).
- Feature 95: (0.15) (width).
- Feature 96: (0.1) (width).
- Feature 97: (0.15) (width).
- Feature 98: (0.1) (width).
- Feature 99: (0.15) (width).
- Feature 100: (0.1) (width).

Side View:

- Overall dimensions: 1.1 MAX (width) x 0.1 (height).
- Feature 1: 4X 0°-12° (chamfer).
- Feature 2: (0.9) (width).
- Feature 3: 0.1 / 0.0 TYP (height).

Top View:

- Overall dimensions: 0.15 (width) x 0.22 / 0.08 TYP (height).
- Feature 1: 4X 4°-15° (chamfer).
- Feature 2: 0.46 / 0.26 TYP (width).
- Feature 3: 8° / 0° TYP (angle).
- Feature 4: SEATING PLANE (plane).
- Feature 5: GAGE PLANE (plane).

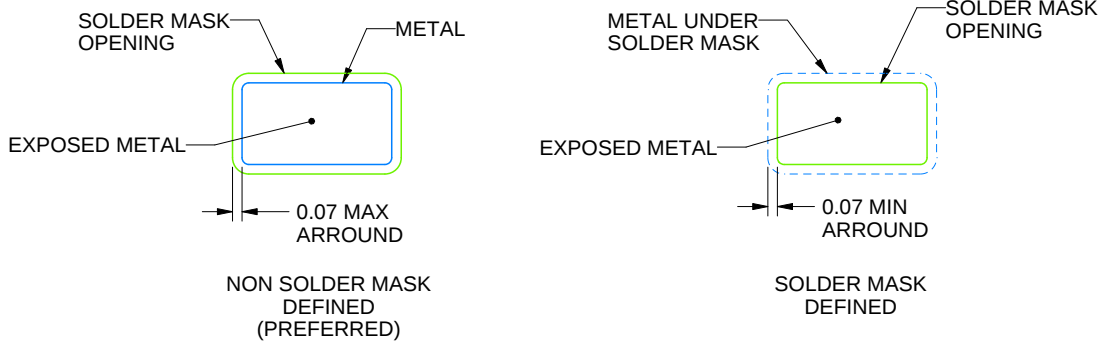
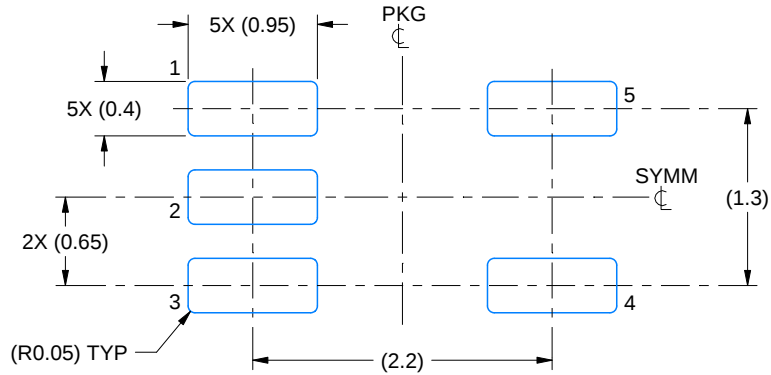
Feature Control Frame:

- Feature: C
- Control: 0.1 M
- Condition: MAXIMUM MATERIAL CONDITION
- Datum: A

Notes:

- NOTE 4: (0.15) (width), (0.1) (width).
- NOTE 5: 5X 0.33 / 0.15 (width).

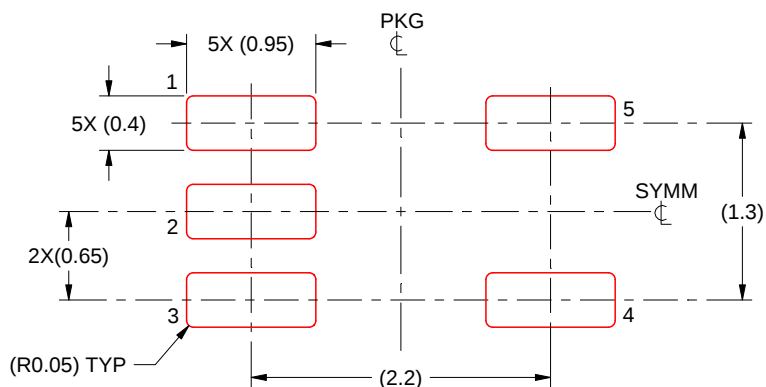
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-203.
4. Support pin may differ or may not be present.
5. Lead width does not comply with JEDEC.
6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side



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NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.
8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

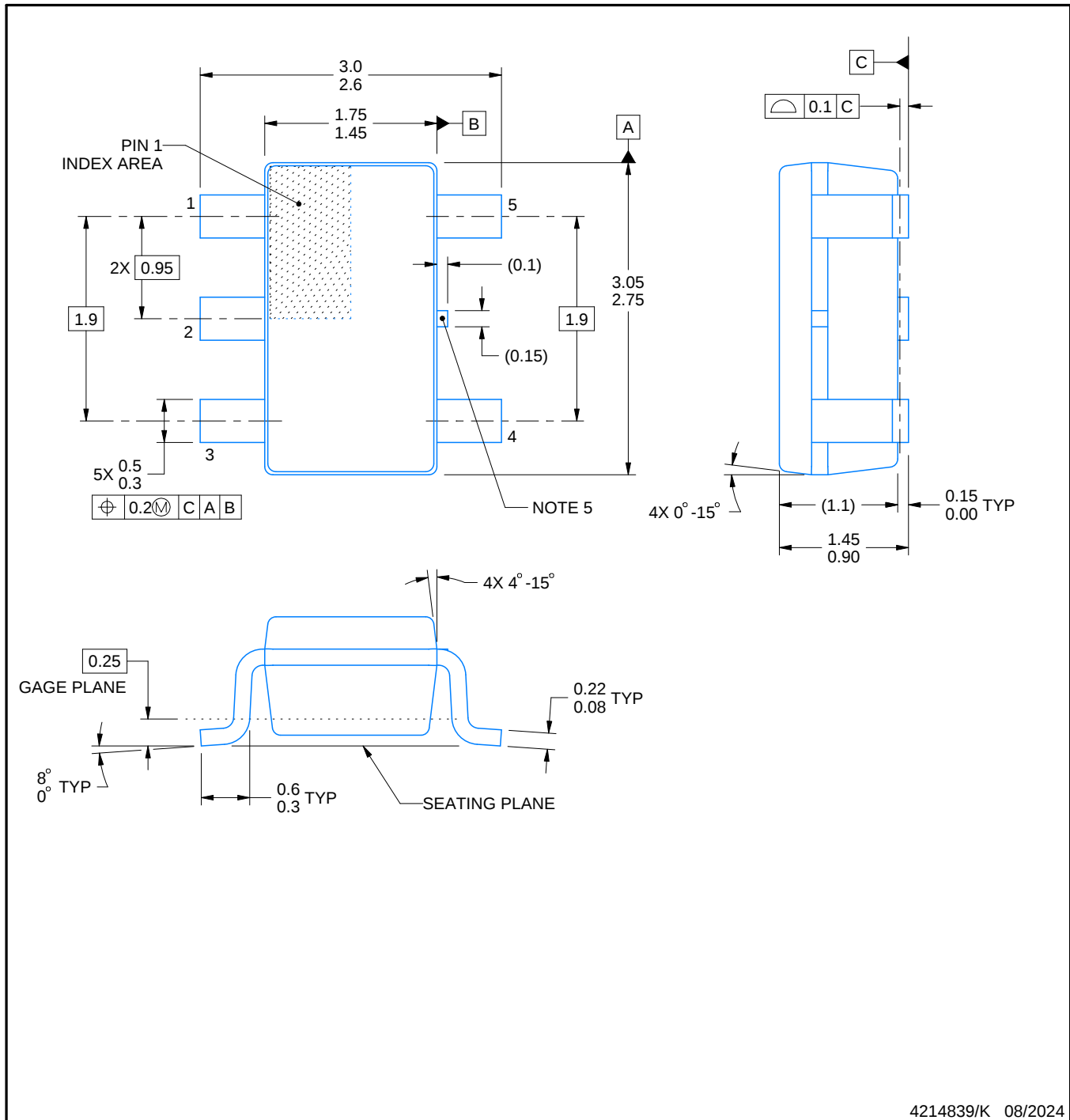


SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

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NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.

EXAMPLE BOARD LAYOUT

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

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NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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